

Bachelor of Science (B.Sc.) Semester—IV (C.B.S.) Examination

PHYSICS (Solid State Electronics and Molecular Physics)

Paper—II

Time : Three Hours]

[Maximum Marks : 50

Note :— (1) All questions are compulsory.

(2) Draw neat diagrams wherever necessary.

EITHER

1. (A) Define h-parameters; obtain fundamental equation of a transistor in C.E mode and draw h-parameter equivalent circuit for it. 5
- (B) (i) Draw the circuit diagram of a common emitter NPN transistor amplifier and explain its working in brief. 3
- (ii) For a transistor the collector current is 10.525 mA, leakage current I_{CBO} is $5 \mu A$ when base current is $100 \mu A$. Calculate the value of β . 2

OR

- (C) Explain the working of NPN transistor. 2½
- (D) Define stability factor. Why does the transistor require special biasing in CE mode ? 2½
- (E) Draw the output characteristics of a transistor, connected in common base mode and explain the three regions. 2½
- (F) A transistor having $h_{ie} = 800 \Omega$, $h_{fe} = 50$, $h_{oe} = 80 \times 10^{-6} \Omega$, and $h_{re} = 2.5 \times 10^{-4}$ is used as a CE amplifier. If load resistance is $5 k\Omega$ and effective source resistance is 500Ω ; calculate the current gain, input impedance and voltage gain. 2½

EITHER

2. (A) What is MOSFET ? State its principle of operation. Explain the construction and working of n-channel depletion MOSFET. 5
- (B) (i) Define three parameters of JFET and hence obtain the relation between them. 3
- (ii) When a reverse gate voltage of 15 V is applied to a JFET, the gate current is $10^{-3} \mu A$. Find the resistance between gate and source. 2

OR

- (C) Draw the circuit diagram of a common source amplifier using a n-channel JFET. Explain its working. 2½
- (D) Explain drain characteristics of a JFET. Define pinch off voltage. 2½
- (E) Calculate the transconductance of JFET with change in drain current 0.3×10^{-3} A and change in gate to source voltage 0.3 V, when drain to source voltage is constant. Also find amplification factor if drain resistance is $33.3 \text{ k}\Omega$. 2½
- (F) Explain the transfer and output characteristics of n-Channel enhancement MOSFET with diagrams. 2½

3. EITHER

- (A) Show that the energy levels of a vibrating diatomic molecule are equidistant. State the selection rule. 5
- (B) (i) Explain various types of molecules based on the principal moments of inertia. 3
- (ii) Find the rotational constant of H_2 molecule if H – H bond is 7.4×10^{-12} meter. 2
- Given : $m_H = 1.67 \times 10^{-27} \text{ kg}$, $h = 6.626 \times 10^{-34} \text{ J-s}$.

OR

- (C) Mention the three types of quantization of molecular energies. According to it explain in short three types of molecular spectra. 2½
- (D) State and explain selection rules for rotation-vibrational spectra of a molecule. Draw the energy level diagram for rotational vibrational spectra and show P, Q & R branches on it. 2½
- (E) The spacing between series of lines in the microwave spectrum of AlH is constant at 12.604 cm^{-1} . Reduced mass of AlH molecules is 0.9718 u . Calculate the inter nuclear distance in the molecules. 2½
- (h = $6.63 \times 10^{-27} \text{ erg-sec}$) 2½
- (1 u = $1.67 \times 10^{-24} \text{ gm}$).
- (F) Explain the intensity distribution of rotational spectral lines. 2½

4. EITHER

- (A) What is ESR spectroscopy ? Explain the principle of electron spin resonance spectroscopy in brief. What are the applications of ESR ?
- (B) (i) Discuss the quantum mechanical explanation of Raman effect.
- (ii) The exciting line in an experimental study of Raman effect is 5460 \AA and Stokes line is 5520 \AA . Find the Raman shift in cm^{-1} .

OR

- (C) What is Raman effect ? What are the characteristics of Raman lines ?
- (D) State and explain Frank-Condon Principle.
- (E) An unpaired electron gives ESR resonance at 35 GHz ; when the magnetic field is 1.3 T , calculate the electron g-factor.

$$(\mu_B = 9.2732 \times 10^{-24} \text{ J/T and } h = 6.626 \times 10^{-34} \text{ J-s}).$$

- (F) What is nuclear magnetic resonance (NMR) ? State at least four applications of NMR.

Attempt any TEN questions :—

- (i) State any two applications of solar cell.
- (ii) Can emitter and collector terminals of BJT transistor be interchanged ? Why ?
- (iii) What is emitted by the emitter of a NPN transistor ? Answer this question for PNP transistor also.
- (iv) Why depletion MOSFET is called as dual mode MOSFET ?
- (v) Why channel is shown by broken line in enhancement MOSFET ?
- (vi) Why does the MOSFET have higher input impedance than JFET ?
- (vii) Why homonuclear molecules do not show rotational spectra ?
- (viii) Spacing between a series of lines in a micro wave spectrum is X . What is the value of rotational constant ?
- (ix) State the Born-Oppenheimer approximation.
- (x) State any two applications of Raman effect.
- (xi) The wavelength of anti-stoke's line in a Raman experiment was found at 5401 \AA . Find the corresponding wave number.
- (xii) What is the basic difference between Raman scattering and Rayleigh scattering ?

 $10 \times 1 = 10$